

Cypress Semiconductor Product Qualification Report

QTP# 97403 VERSION 2.0

August, 2003

Pentium™ and Pentium II™ Clock Synthesizer/Driver	
<small>™ Pentim is a trademark of Intel Corporation</small>	
CY2273	Clock Synthesizer/Driver for Intel 82430TX and Chipsets with 3 DIMM Support
CY2274	Clock Synthesizer/Driver for Intel 82440FX Chipset
CY2275	Clock Synthesizer/Driver for Intel 82440LX Chipsets with 3 DIMM Support
CY2276	Clock Synthesizer/Driver for Intel 82440LX Chipsets with 4 DIMM Support
CY2277	Clock Synthesizer/Driver for Intel 82430TX Chipset
CY2278	Clock Synthesizer/Driver or Mobile PCs

CYPRESS TECHNICAL CONTACT FOR QUALIFICATION DATA:

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PRODUCT DESCRIPTION (for qualification)	
Qualification Purpose: Qualify Fab2 to fabricate CY227x family, commercial products in L28 process.	
Marketing Part #:	CY227*
Package:	48pins SSOP
Device Description:	3.3V Clock Synthesizer/Driver for Pentium and Pentium II
Cypress Division:	Cypress Semiconductor Corporation - CPD Division
Overall Die (or Mask) REV Level (pre-requisite for qualification):	Rev. A
What ID markings on Die:	7C83703A/7C83704A

TECHNOLOGY/FAB PROCESS DESCRIPTION - L28			
Number of Metal Layers:	2	Metal Composition:	Metal 1: 500A Ti/1,200A TiW/6,000A Al/1,200A TiW Metal 2: 1,500A TiW//10,000A Al/150A Ti
Passivation Type and Materials:	3,000A TEOS + 15,000A Si ₂ N ₄		
Free Phosphorus contents in top glass layer(%):	N/A		
Die Coating(s), if used:	N/A		
Generic Process Technology/Design Rule (μ-drawn):	CMOS, Single Poly, Double Metal /0.65 μm		
Gate Oxide Material/Thickness (MOS):	SiO ₂ / 145 A		
Name/Location of Die Fab (prime) Facility:	Cypress Semiconductor - Round Rock, TX		
Die Fab Line ID/Wafer Process ID:	Fab2/L28		

PLASTIC PACKAGE/ASSEMBLY DESCRIPTION			
Package Outline, Type, or Name:	48 Pins SSOP		
Mold Compound Name/Manufacturer:	Hitachi CEL-9200		
Lead Frame material:	Copper		
Lead Finish, composition:	Solder Plated, 85%Sn, 15%Pb		
Die Attach Area Plating:	Solder Plate		
Die Attach Method:	Epoxy	Die Attach Material:	Ablestik 8361H
Wire Bond Method:	Thermosonic	Wire Material/Size:	Gold / 1.0 mil
JESD22-A112 Moisture Sensitivity Level	Level 1		
Assembly Line ID and Process ID:	Cypress Philippines (SSOP)		

Note: Please contact a Cypress Representative for other packages availability.

RELIABILITY TESTS PERFORMED

Stress/Test	Test Condition (Temp/Bias)	Result P/F
Data Bake, Plastic	165°C, No Bias	P
High Temperature Operating Life Early Failure Rate	Dynamic Operating Condition, Vcc = 3.65V, 150°C	P
High Temperature Operating Life Latent Failure Rate	Dynamic Operating Condition, Vcc = 3.65V, 150°C	P
Read & Record Life Test	Dynamic Operating Condition, Vcc = 3.65V, 150°C	
Cold Life Test	-30°C, 6.5V	P
High Temperature Storage	165°C, No Bias	P
High Accelerated Saturation Test (HAST)	140°C, 85%RH, 5.5V Precondition: JESD22 Moisture Sensitivity Level 1 168 Hrs, 85°C/85%RH	P
Temperature Cycle	MIL-STD-883C, Method 1010, Condition C, -65°C to 150°C Precondition: JESD22 Moisture Sensitivity Level 1 168 Hrs, 85°C/85%RH	P
Electrostatic Discharge Human Body Model (ESD-HBM)	4,400V MIL-STD-883, Method 3015.7	P
Electrostatic Discharge Charge Device Model (ESD-CDM)	2,000V Cypress Spec. 25-00020	P
Age Bond Pull Test	MIL-STD-883, Method 2011	P
Latchup Sensitivity	10V In accordance with JEDEC 17. Cypress Spec. 01-00081	P

RELIABILITY FAILURE RATE SUMMARY

Stress/Test	Device Tested/ Device Hours	# Fails	Activation Energy	Thermal ³ A.F	Failure Rate
High Temperature Operating Life Early Failure Rate	850 Devices	0	N/A	N/A	0 PPM
High Temperature Operating Life ^{1,2} Long Term Failure Rate	173,900 DHRs	0	0.7	170	31 FIT

¹ Assuming an ambient temperature of 55°C and a junction temperature rise of 15°C.

² Chi-squared 60% estimations used to calculate the failure rate.

³ Thermal Acceleration Factor is calculated from the Arrhenius equation

$$AF = \exp \left[\frac{E_A}{k} \left[\frac{1}{T_2} - \frac{1}{T_1} \right] \right]$$

where:

E_A = The Activation Energy of the defect mechanism.

k = Boltzmann's constant = 8.62×10^{-5} eV/Kelvin.

T_1 is the junction temperature of the device under stress and T_2 is the junction temperature of the device at use conditions.

RELIABILITY TEST DATA

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DEVICE	ASSY-LOC	FABLOT#	ASSYLOT#	DURATION	S/S	REJ	FAIL MODE
STRESS: DATA BAKE-PLASTIC (165C, NO BIAS)							
CY2273APVC	CSPI-R	2732995	619708289/319	168	78	0	
CY2273APVC	CSPI-R	2732995	619708289/319	552	78	0	
CY2273APVC	CSPI-R	2735423	619709731	168	78	0	
CY2273APVC	CSPI-R	2735423	619709731	552	78	0	
CY2273APVC	CSPI-R	2734307	619709732	168	78	0	
CY2273APVC	CSPI-R	2734307	619709732	552	78	0	
STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-EARLY FAILURE RATE (150C, 3.65V)							
CY2273APVC	CSPI-R	2732995	619708289/319	48	180	0	
CY2273APVC	CSPI-R	2735423	619709731	48	340	0	
CY2273APVC	CSPI-R	2734307	619709732	48	330	0	
STRESS: ESD-CHARGE DEVICE MODEL, 2000V							
CY2273APVC	CSPI-R	2732995	619708289/319	COMP	3	0	
STRESS: ESD-HUMAN BODY CIRCUIT PER MIL STD 883, METHOD 3015, 4000V							
CY2273APVC	CSPI-R	2732995	619708289/319	COMP	3	0	
STRESS: HI-ACCEL SATURATION TEST (140C, 3.63V), PRECOND. 168 HRS 85C/85%RH							
CY2273APVC	CSPI-R	2732995	619708289/319	128	44	0	
CY2273APVC	CSPI-R	2732995	619708289/319	256	44	0	
CY2273APVC	CSPI-R	2734307	619709732	128	45	0	
STRESS: HIGH TEMPERATURE STORAGE (165C, NO BIAS)							
CY2273APVC	CSPI-R	2732995	619708289/319	336	45	0	
CY2273APVC	CSPI-R	2732995	619708289/319	500	45	0	
CY2273APVC	CSPI-R	2732995	619708289/319	1000	45	0	
STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-LATENT FAILURE RATE (150C, 3.65V)							
CY2273APVC	CSPI-R	2732995	619708289/319	80	116	0	
CY2273APVC	CSPI-R	2732995	619708289/319	500	116	0	
CY2273APVC	CSPI-R	2735423	619709731	80	120	0	
CY2273APVC	CSPI-R	2735423	619709731	500	116	0	
CY2273APVC	CSPI-R	2734307	619709732	80	116	0	
CY2273APVC	CSPI-R	2734307	619709732	500	115	0	1 EOS
STRESS: COLD LIFE TEST (-30C, 6.5V)							
CY2273APVC	CSPI-R	2732995	619708289/319	500	45	0	
CY2273APVC	CSPI-R	2732995	619708289/319	1000	44	0	1 EOS
STRESS: READ & RECORD LIFE TEST (150C, 3.65V)							
CY2273APVC	CSPI-R	2734307	619709732	48	10	0	
CY2273APVC	CSPI-R	2734307	619709732	80	10	0	
CY2273APVC	CSPI-R	2734307	619709732	500	10	0	

RELIABILITY TEST DATA

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DEVICE	ASSY-LOC	FABLOT#	ASSYLOT#	DURATION	S/S	REJ	FAIL MODE
STRESS: TC COND. C, -65 TO 150C, PRECOND. 168 HRS 85C/85%RH							
CY2273APVC	CSPI-R	2732995	619708289/319	300	45	0	
CY2273APVC	CSPI-R	2732995	619708289/319	1000	45	0	
CY2273APVC	CSPI-R	2735423	619709731	300	48	0	
CY2273APVC	CSPI-R	2735423	619709731	1000	48	0	
CY2273APVC	CSPI-R	2734307	619709732	300	47	0	
CY2273APVC	CSPI-R	2734307	619709732	1000	47	0	